



VEC2303 — P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Best suited for load switches.
- 1.8V drive.
- Composite type, facilitating high-density mounting.
- Mounting height 0.75mm.

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-12	V
Gate-to-Source Voltage	V_{GSS}		± 8	V
Drain Current (DC)	I_D		-4	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-16	A
Allowable Power Dissipation	P_D	Mounted on a ceramic board (900mm ² X0.8mm)1unit	0.9	W
Total Dissipation	P_T	Mounted on a ceramic board (900mm ² X0.8mm)	1.0	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=-1\text{mA}$, $V_{GS}=0$	-12			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-12\text{V}$, $V_{GS}=0$			-10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 6.4\text{V}$, $V_{DS}=0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=-6\text{V}$, $I_D=-1\text{mA}$	-0.3		-1.0	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-6\text{V}$, $I_D=-2\text{A}$	4.5	7.6		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=-2\text{A}$, $V_{GS}=-4.5\text{V}$		37	49	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=-1\text{A}$, $V_{GS}=-2.5\text{V}$		54	75	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D=-0.3\text{A}$, $V_{GS}=-1.8\text{V}$		76	107	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=-6\text{V}$, $f=1\text{MHz}$		940		pF
Output Capacitance	C_{oss}	$V_{DS}=-6\text{V}$, $f=1\text{MHz}$		230		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=-6\text{V}$, $f=1\text{MHz}$		180		pF

Marking : BC

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SANYO Electric Co.,Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

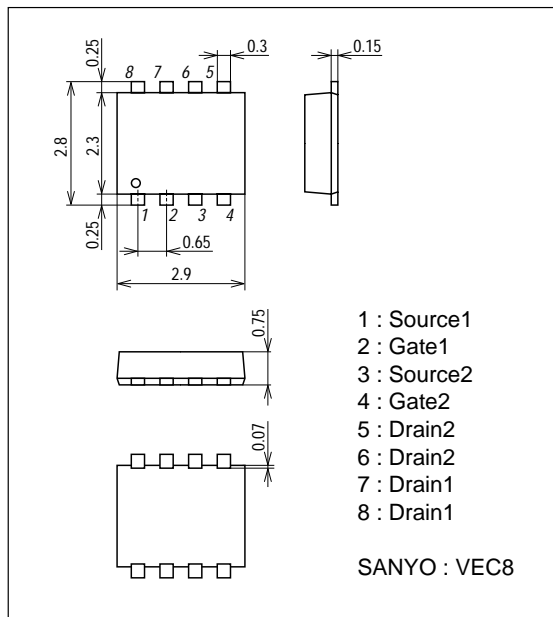
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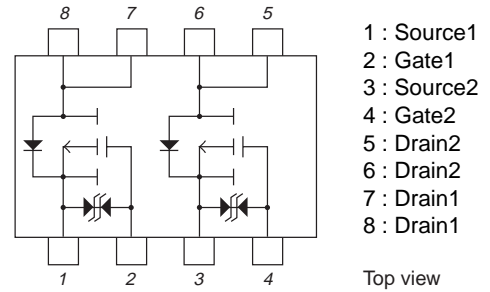
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			min	typ	max	
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		14		ns
Rise Time	t_r	See specified Test Circuit.		120		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit.		97		ns
Fall Time	t_f	See specified Test Circuit.		110		ns
Total Gate Charge	Qg	$V_{DS}=-6V, V_{GS}=-4.5V, I_D=-4A$		11		nC
Gate-to-Source Charge	Qgs	$V_{DS}=-6V, V_{GS}=-4.5V, I_D=-4A$		1.6		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=-6V, V_{GS}=-4.5V, I_D=-4A$		2.8		nC
Diode Forward Voltage	V_{SD}	$I_S=-4A, V_{GS}=0$		-0.85	-1.5	V

Package Dimensions

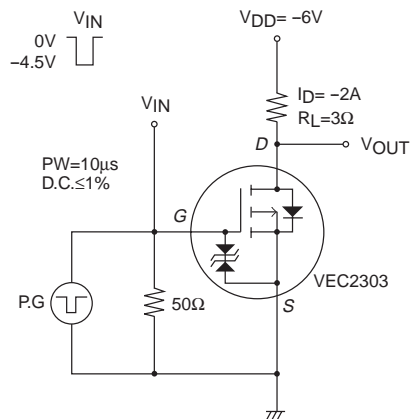
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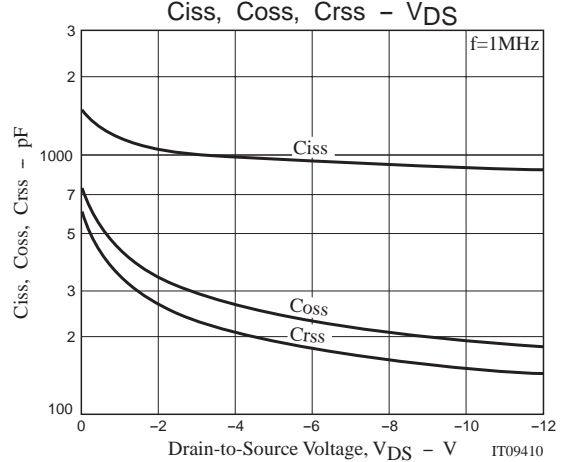
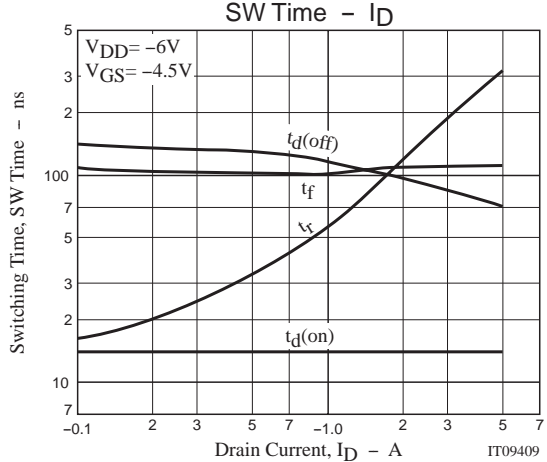
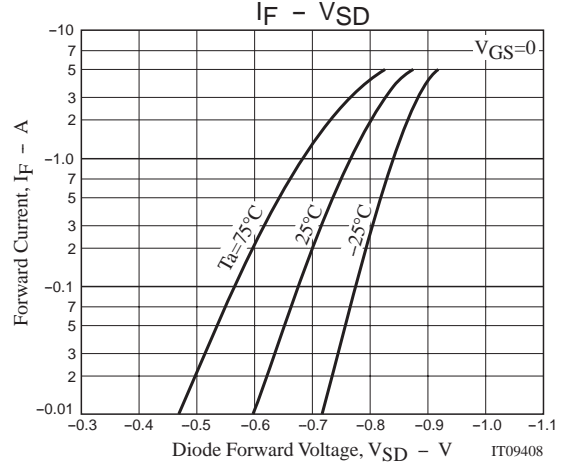
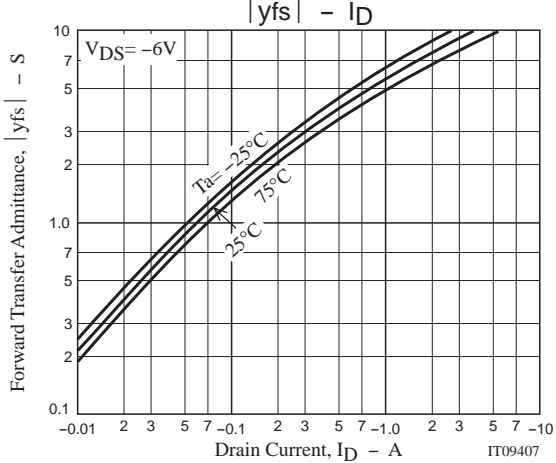
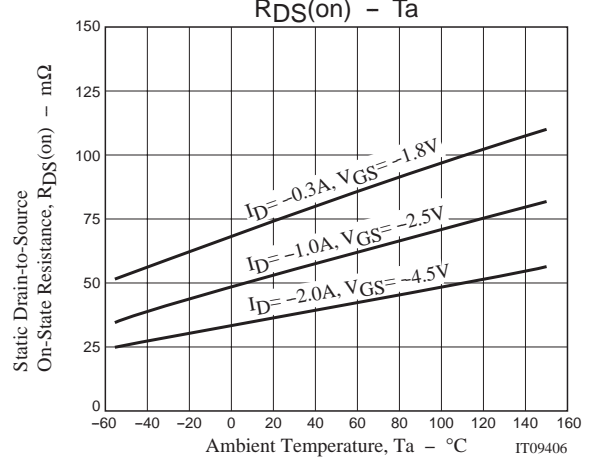
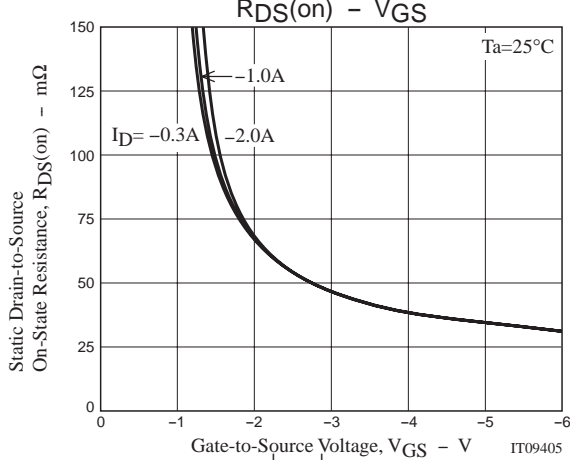
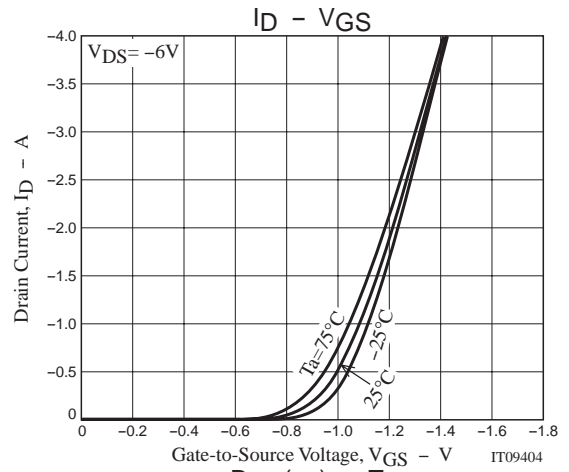
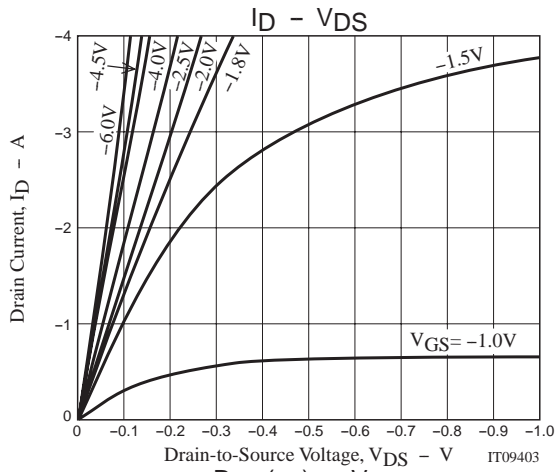
Electrical Connection

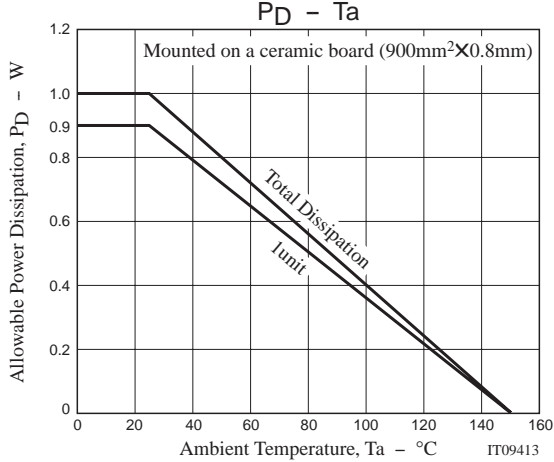
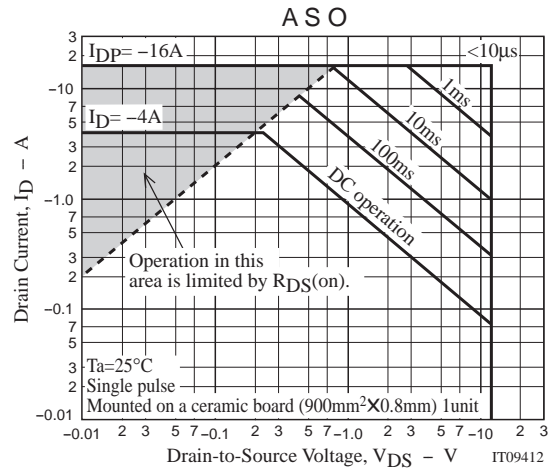
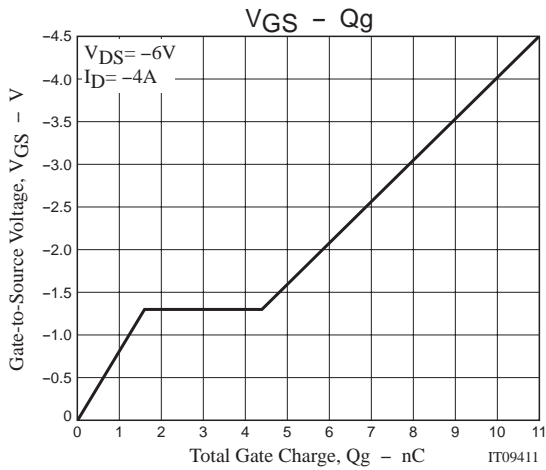


Switching Time Test Circuit



VEC2303





Note on usage : Since the VEC2303 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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